

FEATURES

- SUPPLY VOLTAGE:**
 $V_{CC} = 2.7$ to 3.3 V

- CIRCUIT CURRENT:**
 $I_{CC} = 30$ mA TYP at $V_{CC} = 3.0$ V

- MEDIUM OUTPUT POWER:**
 $P_{O(1dB)} = +9.5$ dBm TYP at $f = 0.9$ GHz
 $P_{O(1dB)} = +9.0$ dBm TYP at $f = 1.9$ GHz
 $P_{O(1dB)} = +8.0$ dBm TYP at $f = 2.4$ GHz

- POWER GAIN:**
 $G_P = 21.5$ dB TYP at $f = 0.9$ GHz
 $G_P = 20.5$ dB TYP at $f = 1.9$ GHz
 $G_P = 20.5$ dB TYP at $f = 2.4$ GHz

- UPPER LIMIT OPERATING FREQUENCY:**
 $f_U = 2.9$ GHz TYP at 3 dB bandwidth

- HIGH-DENSITY SURFACE MOUNTING:**
6-pin super minimold package ($2.0 \times 1.25 \times 0.9$ mm)

DESCRIPTION

The UPC8182TB is a silicon monolithic integrated circuit designed as amplifier for mobile communications. This IC has low current consumption and wider band than UPC2771TB.

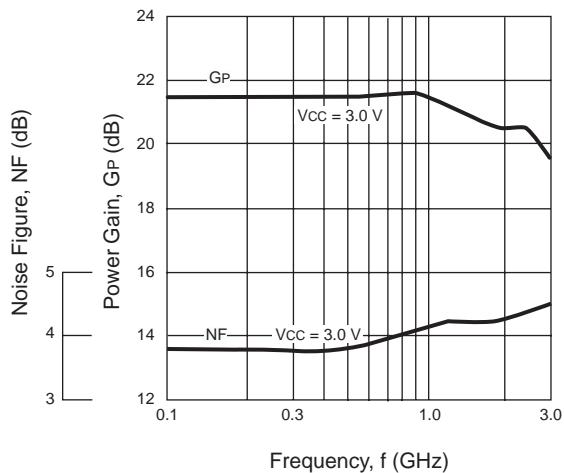
This IC is manufactured using NEC's 25 GHz ft UHSO silicon bipolar process. This process uses direct silicon nitride passivation film and gold electrodes. These materials can protect the chip surface from pollution and prevent corrosion/migration. This IC has excellent performance, uniformity, and reliability.

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$, $V_{CC} = 3.0$ V, $Z_S = Z_L = 50\Omega$)

PART NUMBER PACKAGE OUTLINE			UPC8182TB S06		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
I_{CC}	Circuit Current (no signal)	mA	22.0	30.0	38.0
G_P	Power Gain, $f = 0.9$ GHz $f = 1.9$ GHz $f = 2.4$ GHz	dB	19.0 17.5 18.0	21.5 20.5 20.5	25.0 23.5 24.0
NF	Noise Figure, $f = 0.9$ GHz $f = 1.9$ GHz $f = 2.4$ GHz	dB	— — —	4.5 4.5 5.0	6.0 6.0 6.5
f_U	Upper Limit Operating Frequency, 3 dB down below from gain at $f = 1.0$ GHz	GHz	2.8	2.9	—
ISL	Isolation, $f = 0.9$ GHz $f = 1.9$ GHz $f = 2.4$ GHz	dB	30 27 28	33 32 31	— — —

NOISE FIGURE, POWER GAIN vs.
FREQUENCY



APPLICATIONS

- Buffer amplifiers for 1.9 GHz to 2.4 GHz mobile communication system.

ELECTRICAL CHARACTERISTICS, cont.

(TA = 25°C, Vcc = Vout = 3.0 V, Zs = ZL = 50Ω)

PART NUMBER PACKAGE OUTLINE			UPC8182TB S06		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
RLin	Input Return Loss, f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dB	6	8	—
			8	10	—
			9	12	—
RLout	Output Return Loss, f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dB	8	10	—
			9	11	—
			11	14	—
PO(1dB)	1 dB Gain Compression Output Level, f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dBm	+7.5	+9.5	—
			+7.0	+9.0	—
			+5.5	+8.0	—
PO(SAT)	Saturated Output Power Level, f = 0.9 GHz, PIN = -5 dBm f = 1.9 GHz, PIN = -5 dBm f = 2.4 GHz, PIN = -5 dBm	dBm	—	+10.5	—
			—	+10.0	—
			—	+9.5	—

ABSOLUTE MAXIMUM RATINGS¹ (TA = +25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Vcc	Supply Voltage ²	V	3.6
Icc	Total Circuit Current	mA	60
Pd	Power Dissipation ³	mW	200
TA	Operating Ambient Temperature	°C	-40 to +85
Tstg	Storage Temperature	°C	-55 to +150
PIN	Input Power	dBm	+10

Notes:

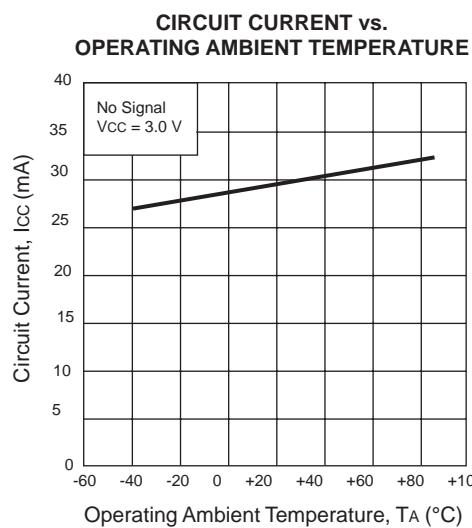
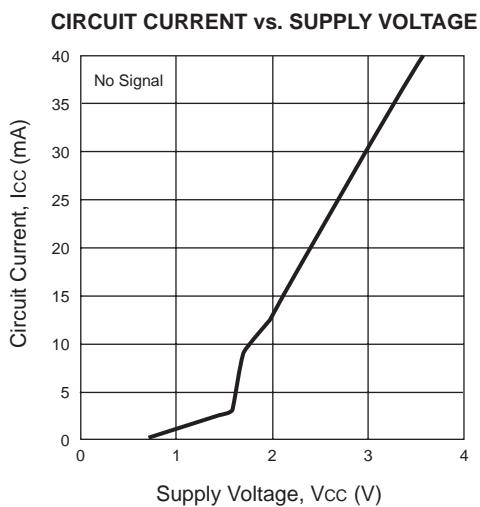
1. Operation in excess of any one of these conditions may result in permanent damage.
2. TA = 25°C, pins 4 and 6.
3. Mounted on a double-sided copper clad 50x50x1.6 mm epoxy glass PWB, TA = +85°C.

RECOMMENDED OPERATING CONDITIONS

SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
Vcc	Supply Voltage ¹	V	2.7	3.0	3.3
TA	Ambient Temperature	°C	-40	+25	+85

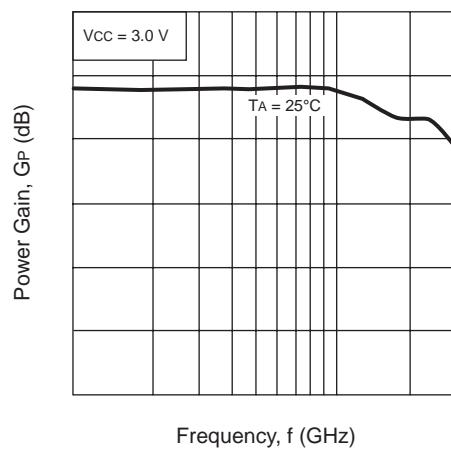
Note:

1. Same voltage applied to pins 4 and 6

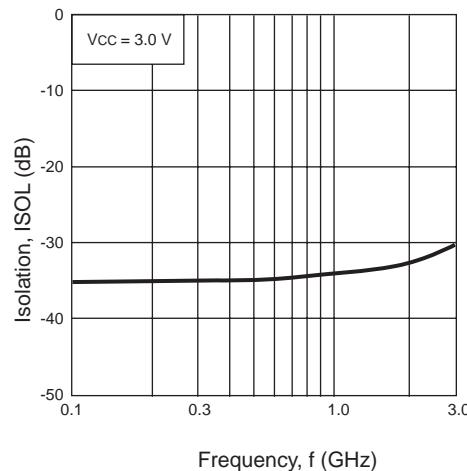
TYPICAL PERFORMANCE CURVES (Unless otherwise specified, TA = 25°C)

TYPICAL PERFORMANCE CURVES, cont. (Unless otherwise specified, TA = 25°C)

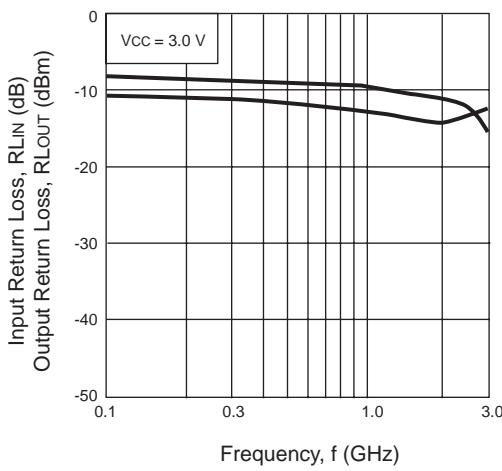
**POWER GAIN vs.
FREQUENCY**



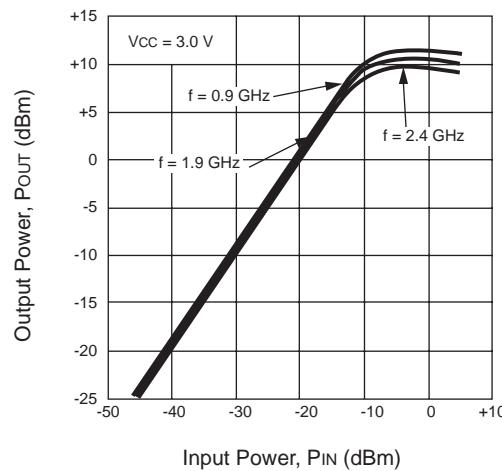
ISOLATION vs. FREQUENCY



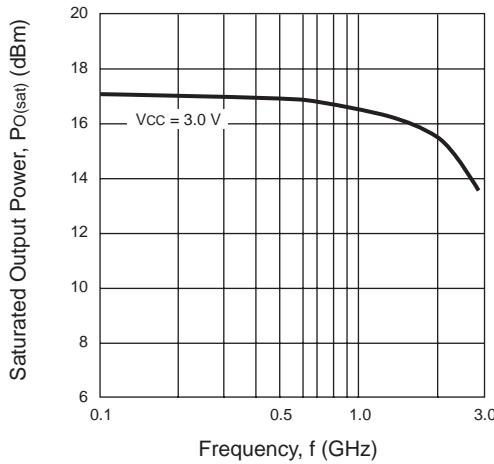
**INPUT RETURN LOSS, OUTPUT RETURN LOSS vs.
FREQUENCY**



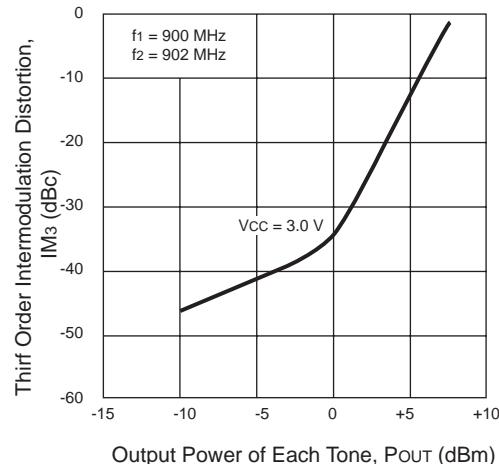
OUTPUT POWER vs. INPUT POWER

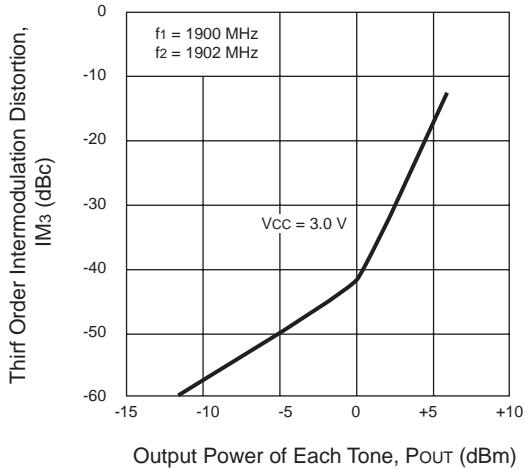
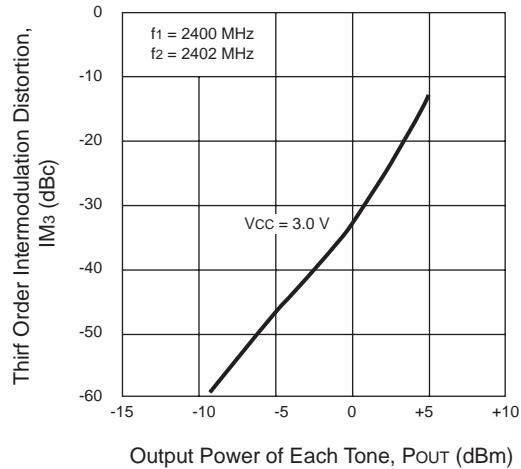


**SATURATED OUTPUT POWER vs.
FREQUENCY**

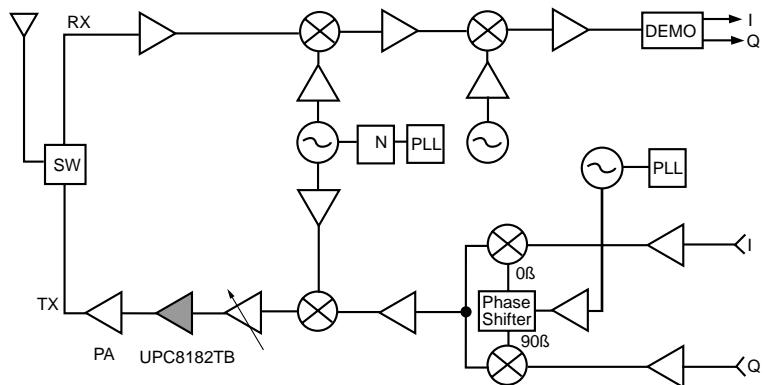


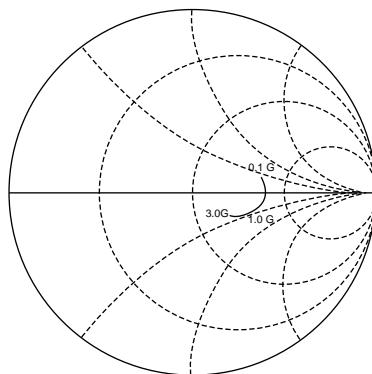
**THIRD ORDER INTERMODULATION DISTORTION vs.
OUTPUT POWER OF EACH TONE**



TYPICAL PERFORMANCE CURVES (Unless otherwise specified, TA = 25°C)THIRD ORDER INTERMODULATION DISTORTION vs.
OUTPUT POWER OF EACH TONETHIRD ORDER INTERMODULATION DISTORTION vs.
OUTPUT POWER OF EACH TONE**PIN FUNCTIONS** (Pin Voltage is measured at Vcc = 3.0 V)

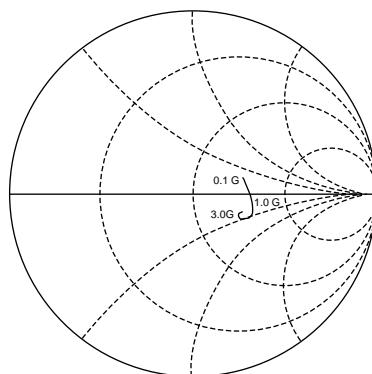
Pin No.	Pin Name	Applied Voltage	Pin Voltage	Description	Equivalent Circuit
1	INPUT	—	—	Signal input pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band. A multi- feedback circuit is designed to cancel the deviations of hFE and resistance. This pin must be coupled to signal source with capacitor for DC cut.	
4	OUTPUT	Voltage same as Vcc through external inductor	—	Signal output pin. The inductor must be attached between Vcc and output pins to supply current to the internal output transistors.	
6	Vcc	2.7 to 3.3	—	Power supply pin, which biases the internal input transistor. This pin should be externally equipped with bypass capacitor to minimize its impedance.	
2 3 5	GND	0	—	GND pin. This pin should be connected to the system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to decrease impedance difference.	

APPLICATION EXAMPLE (Digital Cellular Telephone)

TYPICAL SCATTERING PARAMETERS ($T_A = 25^\circ\text{C}$)

S11

Frequency in GHz
V_{cc} = V_{out} = 3.0 V, I_{cc} = 30.0 mA

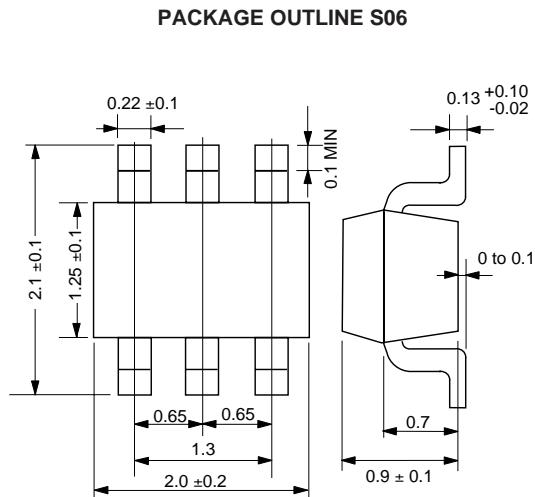


S22

V_{cc} = V_{out} = 3.0 V, I_{cc} = 30.0 mA

FREQUENCY GHz	S ₁₁		S ₂₁		S ₁₂		S ₂₂		K
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	
0.1	0.452	-2.7	9.078	-2.0	0.020	4.3	0.338	-1.6	1.89
0.1	0.391	-2.6	12.933	-4.4	0.016	1.8	0.293	-2.7	1.84
0.2	0.391	-6.2	12.999	-8.0	0.017	3.5	0.287	-5.1	1.80
0.3	0.387	-10.2	13.174	-11.8	0.016	7.6	0.282	-6.8	1.86
0.4	0.382	-13.8	13.322	-16.4	0.016	9.2	0.279	-8.4	1.82
0.5	0.371	-16.7	13.391	-20.7	0.017	13.2	0.276	-9.1	1.79
0.6	0.365	-19.5	13.407	-25.7	0.017	15.9	0.279	-10.0	1.78
0.7	0.354	-21.6	13.549	-30.4	0.018	21.0	0.278	-11.0	1.73
0.8	0.347	-23.7	13.475	-35.3	0.020	22.3	0.285	-11.7	1.57
0.9	0.343	-25.8	13.426	-40.1	0.020	21.2	0.290	-13.5	1.52
1.0	0.334	-28.1	13.474	-44.9	0.019	27.0	0.293	-15.1	1.62
1.1	0.330	-30.8	13.386	-50.0	0.018	28.1	0.296	-17.6	1.69
1.2	0.324	-32.1	13.185	-54.6	0.020	27.6	0.302	-20.3	1.61
1.3	0.317	-34.2	13.121	-59.4	0.020	31.7	0.303	-21.9	1.62
1.4	0.318	-35.7	13.151	-64.2	0.021	32.1	0.309	-24.6	1.51
1.5	0.313	-38.0	12.866	-69.4	0.022	34.0	0.315	-27.1	1.47
1.6	0.309	-39.8	12.814	-73.9	0.023	34.6	0.318	-29.5	1.43
1.7	0.303	-42.5	12.508	-78.2	0.022	34.3	0.314	-33.1	1.52
1.8	0.302	-44.3	12.357	-83.2	0.024	35.9	0.319	-35.6	1.44
1.9	0.298	-45.5	12.090	-86.7	0.026	36.9	0.322	-37.6	1.39
2.0	0.290	-47.5	12.035	-90.9	0.025	40.0	0.313	-40.5	1.43
2.1	0.291	-50.1	11.984	-95.4	0.027	36.5	0.321	-43.5	1.36
2.2	0.283	-52.6	11.662	-99.9	0.026	38.2	0.314	-46.0	1.43
2.3	0.277	-54.1	11.711	-104.0	0.027	40.0	0.310	-48.6	1.41
2.4	0.274	-56.7	11.629	-108.6	0.028	38.4	0.309	-51.6	1.37
2.5	0.270	-58.0	11.475	-113.7	0.029	39.1	0.304	-54.1	1.35
2.6	0.261	-59.8	11.308	-118.5	0.029	39.9	0.297	-55.3	1.39
2.7	0.264	-61.4	11.198	-123.5	0.032	38.6	0.303	-56.5	1.29
2.8	0.253	-62.0	10.803	-129.4	0.031	42.8	0.295	-57.3	1.39
2.9	0.258	-63.9	10.670	-134.8	0.032	41.3	0.307	-57.9	1.33
3.0	0.255	-65.7	10.086	-139.5	0.033	40.9	0.316	-60.0	1.35
3.1	0.250	-67.9	9.683	-145.4	0.032	39.8	0.321	-63.1	1.44

OUTLINE DIMENSIONS (Units in mm)

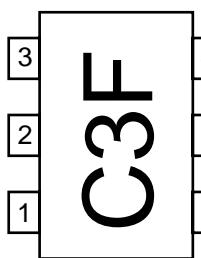


Note:

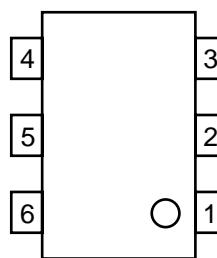
All dimensions are typical unless otherwise specified.

LEAD CONNECTIONS

(Top View)

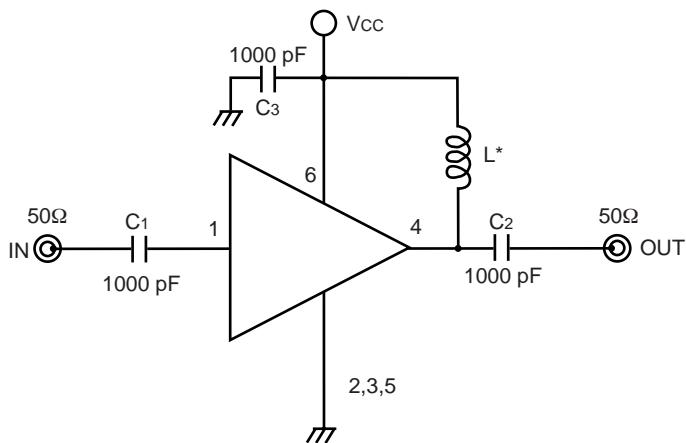


(Bottom View)



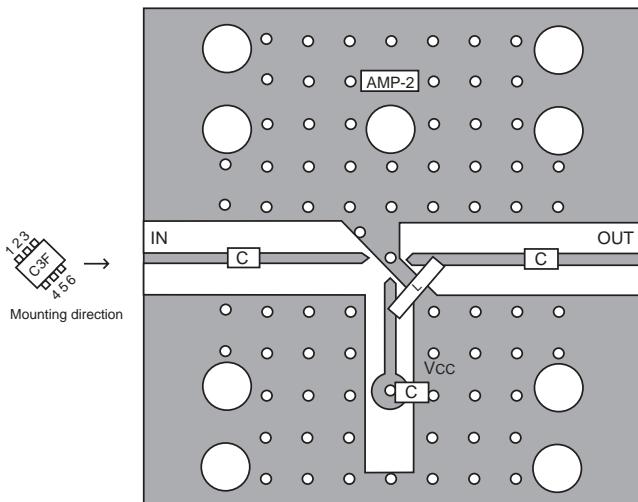
1. INPUT
2. GND
3. GND
4. OUTPUT
5. GND
6. Vcc

TEST CIRCUIT



*L: 100 nH for $f = 100$ MHz and higher
10 nH for $f = 2.0$ GHz and higher

APPLICATION BOARD



Life Support Applications

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